

PLASTIC SILICON RECTIFIERS

REVERSE VOLTAGE - **50 to 1000** Volts
FORWARD CURRENT - **10** Amperes

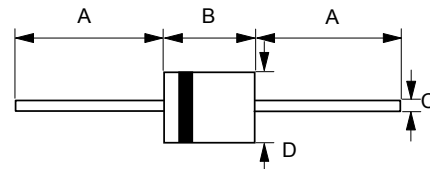
FEATURES

- Low cost
- Diffused junction
- Low forward voltage drop
- Low reverse leakage current
- High current capability
- The plastic material carries UL recognition 94V-0

MECHANICAL DATA

- Case : JEDEC R-6 molded plastic
- Polarity : Color band denotes cathode
- Weight : 0.07 ounces, 2.1 grams
- Mounting position : Any

R-6



R-6		
Dim.	Min.	Max.
A	25.4	-
B	8.60	9.10
C	1.20 $\varnothing$	1.30 $\varnothing$
D	8.60 $\varnothing$	9.10 $\varnothing$
All Dimensions in millimeter		

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.
Single phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%

CHARACTERISTICS	SYMBOL	LT10A01	LT10A02	LT10A03	LT10A04	LT10A05	LT10A06	LT10A07	UNIT
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current @ $T_A=50^\circ\text{C}$	$I_{(AV)}$	10.0							A
Peak Forward Surge Current 8.3ms single half sine-wave super imposed on rated load	I_{FSM}	600							A
Maximum forward Voltage at 10A DC	V_F	1.0							V
Maximum DC Reverse Current at Rated DC Blocking Voltage @ $T_J=25^\circ\text{C}$ @ $T_J=100^\circ\text{C}$	I_R	10 100							μA
Typical Junction Capacitance (Note 1)	C_J	150							pF
Typical Thermal Resistance (Note 2)	$R_{\theta JA}$	10							$^\circ\text{C/W}$
Operating Temperature Range	T_J	-55 to +125							$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-55 to +150							$^\circ\text{C}$

NOTES : 1.Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
2.Thermal Resistance Junction to Ambient.

REV. 3, Jul-2004, KDAG02

